

# Infrared Nonlinear Optical Polymorphs $\alpha$ - and $\beta$ -SrCu<sub>2</sub>SnS<sub>4</sub> Exhibiting Large Second Harmonic Generation Responses with Requisite Phase-Matching Behavior

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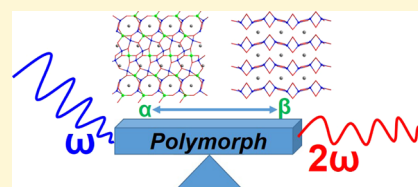


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Supporting Information

**ABSTRACT:**  $\alpha$ - and  $\beta$ -SrCu<sub>2</sub>SnS<sub>4</sub> polymorphs, exhibiting special structural changes and excellent physicochemical performances, were successfully synthesized and characterized as promising IR NLO candidates. Note that they satisfy the essential phase-matching condition and have strong SHG responses about 0.7 and 1.0 times those of benchmark AgGaS<sub>2</sub> under 2.09  $\mu$ m incident light, respectively, which agree well with the theoretical SHG coefficients and suitable birefringences based on first-principles calculation. Moreover, it is also verified that their SHG effects originate from the synergetic contribution between CuS<sub>4</sub> and SnS<sub>4</sub> ligands after the SHG density calculations.



Inorganic functional materials have been widely explored in recent decades and applied in many key technology regions because of their multiple structures and attractive performances, especially for the laser frequency conversion.<sup>1–20</sup> Metal chalcogenides exhibit red-shifted stretching frequencies and high polarizability than oxides that are more beneficial for infrared laser application.<sup>21–35</sup> As for polymorphism, they adopt identical chemical compositions but special structural changes, providing an effective route to study the relationship between structure and performance.<sup>36–40</sup> So far, numerous polymorphs have been discovered in the quaternary diamond-like semiconductors (DLSs), such as the typical I<sub>2</sub>–II–IV–Q<sub>4</sub> (I = monovalent cations; II = bivalent cations; IV = Si, Ge, Sn; Q = S, Se) DLSs system.<sup>41</sup> Note that several of them undergo an interesting change in the coordination of tetrahedral stacking and show potential application as infrared nonlinear optical (IR NLO) materials with excellent physicochemical properties. For instance, both Cu<sub>2</sub>ZnSiS<sub>4</sub> polymorphs ( $\alpha$ : *Pmn*<sub>21</sub> and  $\beta$ : *Pn*) display good second harmonic generation (SHG) responses (1.2  $\times$  benchmark AgGaS<sub>2</sub>) under 1.55  $\mu$ m incident light;<sup>42</sup> besides,  $\alpha$ - and  $\beta$ -Li<sub>2</sub>MnSnS<sub>4</sub> (*Pna*<sub>21</sub> vs *Pn*) have moderate SHG effects of about 0.4  $\times$  AgGaS<sub>2</sub>@2.1  $\mu$ m.<sup>43</sup> Except for the above-mentioned DLS system, multiple structural changes also appeared in the similar I<sub>2</sub>–Ba/Sr/Pb/Eu–IV–Q<sub>4</sub> system with different IV or VI atoms and only one polymorph, Cu<sub>2</sub>BaSnSe<sub>4</sub> ( $\alpha$ : *P3*<sub>21</sub> vs  $\beta$ : *Ama*<sub>2</sub>), was found in the above system.<sup>44–46</sup> A detailed literature survey indicates that different sintering temperatures or starting ingredients are in favor of producing various coordination environments of structural ligands, and these structural modifications proceed extremely slowly, leading to the preservation of a metastable phase in view of their high energy barriers. Based on the above analysis, in this work, other polymorphs,  $\alpha$ - and  $\beta$ -SrCu<sub>2</sub>SnS<sub>4</sub> ( $\alpha$ : *P3*<sub>21</sub> vs  $\beta$ : *Ama*<sub>2</sub>), were successfully synthesized, and these

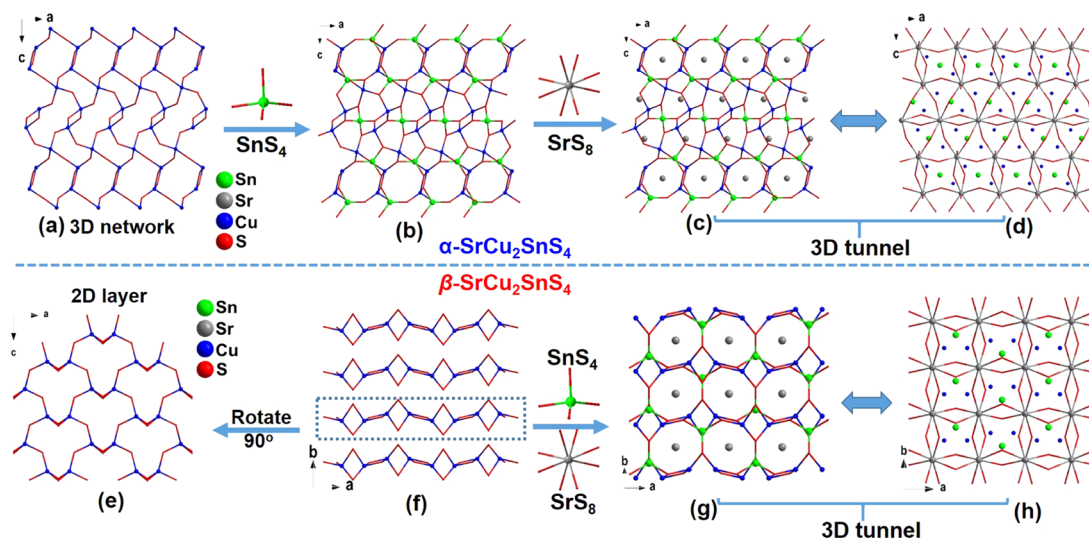
polymorphisms are the first discovered examples of the I<sub>2</sub>–Sr–IV–VI<sub>4</sub> system. Both of them exhibit good SHG responses that are about 0.7 and 1.0 times the benchmark AgGaS<sub>2</sub> and satisfy the phase-matching demand, indicating that they can be expected as promising IR NLO candidates. The first-principles calculation also verifies that the calculated results (NLO coefficients and birefringence) are in agreement with the experimental values. Meanwhile, the combined contribution of CuS<sub>4</sub> and SnS<sub>4</sub> ligands achieves the origin of their large SHG responses by means of the SHG density calculations.

Single-crystal X-ray diffraction test shows that they crystallize in the *P3*<sub>21</sub> space group of the trigonal system for  $\alpha$ -phase and orthorhombic *Ama*<sub>2</sub> for  $\beta$ -phase (Tables S1 and S3). The  $\alpha$ -phase was discovered in 1976 by Teske, but its critical NLO properties have not been reported.<sup>47</sup> Note that the  $\beta$ -phase has been successfully synthesized for the first time. Herein, we have systematically studied the structural modifications between the two phases. As for the  $\alpha$ -phase, its asymmetric unit is composed of one Sr, one Sn, two Cu, and four S atoms. In its structure, CuS<sub>4</sub> units with  $d(\text{Cu}–\text{S}) = 2.278–2.407$  Å connect together by sharing corners and edges to form three types of 3D channels including 4-member ring (4-MR), 8-MR, and 12-MR (Figure 1a), and then further link with SnS<sub>4</sub> ligands ( $d(\text{Sn}–\text{S}) = 2.375–2.397$  Å) to surround the roughly circular 3D channels in which Sr atoms are located (Figure 1b,c). From another point of view, SrS<sub>8</sub> dodecahedra also link with each other to form irregular 3D tunnels, where Cu and Sn atoms are located (Figure 1d). As for the  $\beta$ -phase,

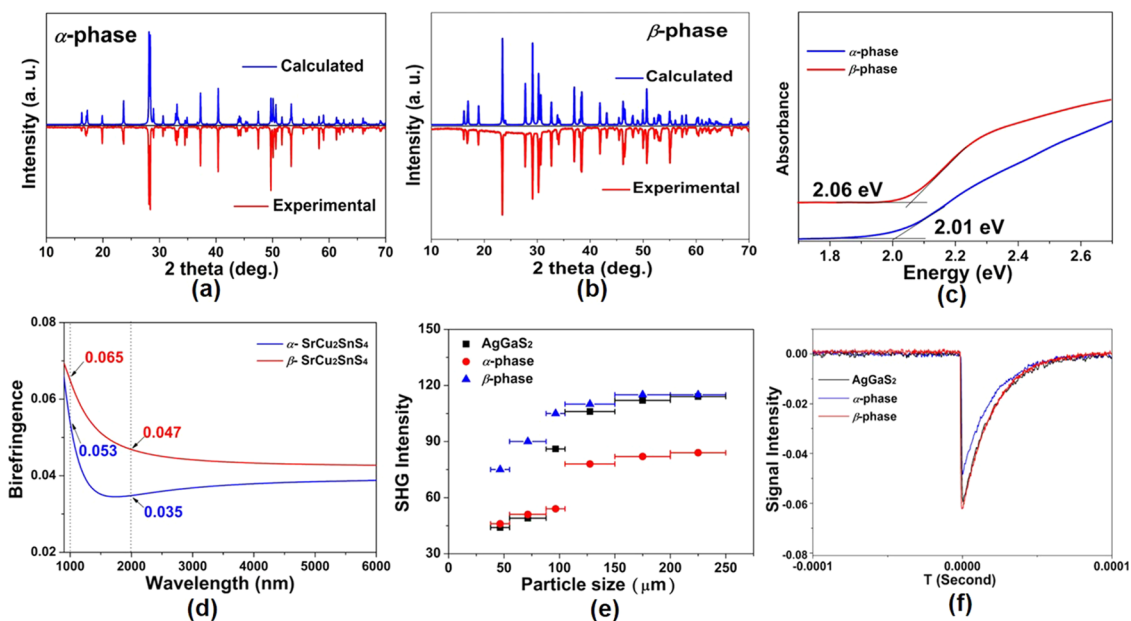
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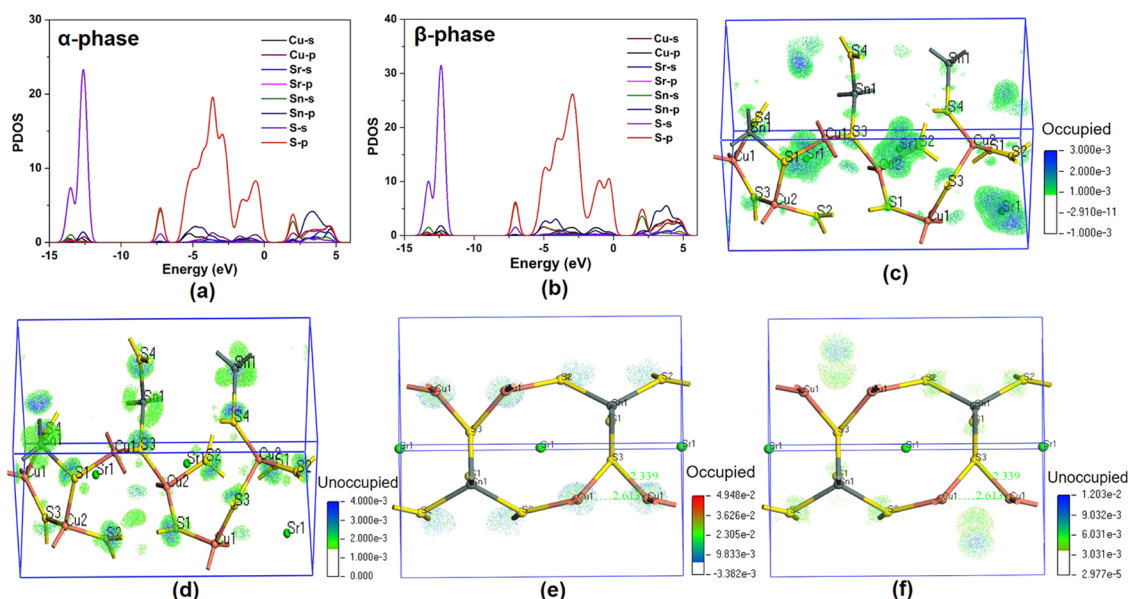
**Figure 1.** Structural modifications between  $\alpha$ - and  $\beta$ - $\text{SrCu}_2\text{SnS}_4$ .  $\alpha$ -Phase: (a) 3D network formed by  $\text{Cu}_4$  ligands; (b) combination of  $\text{Cu}_4$  and  $\text{SnS}_4$  ligands; (c) structure view from the  $b$ -axis ( $\text{Sr-S}$  bonds were omitted); and (d) structure view from the  $b$ -axis ( $\text{Cu-S}$  and  $\text{Sn-S}$  bonds were omitted).  $\beta$ -Phase: (e) 2D layer formed by  $\text{Cu}_4$  ligands; (f) 2D layers stacked along the  $b$ -axis; (g) 3D network structure ( $\text{Sr-S}$  bonds were omitted); and (h) 3D network formed by  $\text{SrS}_8$  ligands ( $\text{Cu-S}$  and  $\text{Sn-S}$  bonds were omitted).



**Figure 2.** (a, b) PXR D patterns. (c) Experimental band gaps. (d) Birefringence versus wavelength. (e) Curves of SHG response versus particle size ( $\text{AgGaS}_2$  as the reference). (f) SHG signals (voltage) diagram of title crystals and  $\text{AgGaS}_2$ .

2D layers composed of corner- and edge-sharing  $\text{Cu}_4$  ligands with  $d(\text{Cu-S}) = 2.314\text{--}2.503$  Å stack along the  $b$ -direction, which are different from the 3D network found in the  $\alpha$ -phase (Figure 1e). Adjacent  $(\text{Cu}_4)_n$  layers are interconnected by isolated  $\text{SnS}_4$  ligands with  $d(\text{Sn-S}) = 2.377\text{--}2.415$  Å to compose 3D regular tunnels along the  $c$ -axis; similarly,  $\text{SrS}_8$  dodecahedra are also interlinked together to form regular 3D tunnels, which is also different from the irregular 3D network in the  $\alpha$ -phase (Figure 1f–h). Survey on the  $\text{I}_2\text{--Sr/Ba--IV--Q}_4$  system shows that these compounds undergo multiple structural changes with different IV or Q atoms, such as orthorhombic to trigonal ( $\text{Ama}2$  to  $\text{P}3_22_1$  or  $\text{P}3_12_1$ ),<sup>44</sup> orthorhombic to tetragonal ( $\text{I}222$  to  $\text{I}\bar{4}2m$ ),<sup>48</sup> and tetragonal to trigonal ( $\text{I}\bar{4}2d$  to  $\text{R}3c$ ).<sup>49</sup> So far, only one polymorphism,  $\text{Cu}_2\text{BaSnSe}_4$  ( $\alpha$ :  $\text{P}3_22_1$  vs  $\beta$ :  $\text{Ama}2$ ), was found in the above

system, which is similar to that in title compounds. Extending the survey to the  $\text{I}_2\text{--II--IV--Q}_4$  DLSs system shows that seven polymorphs were discovered and show various structural changes including monoclinic to orthorhombic ( $\text{Cu}_2\text{ZnSnS}_4$ :  $\text{Pn}$  vs  $\text{Pmn}2_1$ ),<sup>42</sup> orthorhombic to orthorhombic ( $\text{Ag}_2\text{CdGeS}_4$ :  $\text{Pmn}2_1$  vs  $\text{Pna}2_1$ ),<sup>50,51</sup> orthorhombic to tetragonal ( $\text{Cu}_2\text{ZnGeS}_4$ :  $\text{Pmn}2_1$  vs  $\text{I}\bar{4}2m$ ),<sup>52,53</sup> and tetragonal to tetragonal ( $\text{Cu}_2\text{ZnSnS}_4$ :  $\text{I}\bar{4}2m$  vs  $\text{I}\bar{4}$ )<sup>54,55</sup> (Table S2). A comparison of their structures shows that the direction of the arrangement of  $\text{IQ}_4$  units is obviously different, leading to the structural transformation and further inducing multiple phases.<sup>56</sup> Based on different space groups ( $\text{Pmn}2_1$ ,  $\text{Pn}$ ,  $\text{Pna}2_1$ ,  $\text{I}\bar{4}2m$ , and  $\text{I}\bar{4}$ ), five kinds of structural changes on the link modes of monovalent-cation-centered tetrahedral ligands exist; for instance, a 2D layer, comprising monovalent-cation-



**Figure 3.** (a, b) Partial density of states (PDOS) for title crystals. (c, d) SHG density of  $\alpha$ -phase at the occupied and unoccupied states. (e, f) SHG density of  $\beta$ -phase at the occupied and unoccupied states.

centered tetrahedral ligands by corner-sharing S atoms, located at the  $ac$ -plane in  $Pmn2_1$ ; a 3D framework structure, comprising six-tetrahedra surrounded channels, located at the  $bc$ -plane in  $Pn$ ; 3D framework structure, comprising eight-tetrahedra surrounded channels, located at the  $ab$  plane in  $Pna2_1$ ; tetrahedral-formed 2D layer located at the  $ab$  plane in  $\bar{I}42m$ ; and disordered atomic occupations in the  $\bar{I}4$ . As for the  $\text{Cu}_2\text{-Sr-IV-Q}_4$  system, four compounds were discovered including  $\text{SrCu}_2\text{M}^{\text{IV}}\text{Q}_4$  ( $\text{IV} = \text{Ge, Sn; Q} = \text{S, Se}$ ) that crystallize in two different space groups:  $\text{Ama}2$  vs  $\text{P}3_22_1$ .<sup>57,58</sup> In other words,  $\alpha$ - and  $\beta$ - $\text{SrCu}_2\text{SnS}_4$  can be viewed as the first discovered polymorphism in the  $\text{I}_2\text{-Sr-IV-VI}_4$  system. Based on the above analysis, the arrangement modes of  $d^{10}$ -element-centered tetrahedra may produce an enormous effect on regulating the phase transition, which also gives us a good inspiration to design and predict new polymorphisms.

Title crystals with red color were prepared by the spontaneous crystallization method in vacuum-sealed silica tubes (see detail in the SI). Note that their high yields ( $\sim 95\%$ ) were achieved after repeated grinding and calcination. Both of them are stable in the air for several months. Their experimental powder XRD patterns are in agreement with the theoretical data, which ensure the accuracy of the following test results (Figure 2a,b). We have also measured their thermal properties in the vacuum-sealed silica tubes (Figure S1). As for the orthorhombic phase ( $\beta$ ), its melting and crystallization temperatures are 771 and 741  $^\circ\text{C}$ , respectively, and no phase-transformation phenomenon has been found in its DSC curve. Besides, we have also measured their PXRD patterns at four different sintering temperatures (700, 800, 900, and 1000  $^\circ\text{C}$ ) for previously prepared orthorhombic phase samples (Figure S2), and all of them agree well with the theoretical XRD data ( $\beta$ -phase) and no  $\alpha$ -phase patterns were observed. Moreover, as for  $\alpha$ -phase, its DSC curve shows the melting and crystallization temperatures of 774 and 744  $^\circ\text{C}$ , respectively, with the phase transition point (from  $\alpha$ - to  $\beta$ -phase) at 672  $^\circ\text{C}$ , which is also verified by the experimental PXRD patterns at different sintering temperatures. Note that  $\alpha$ -phase is changed to  $\beta$ -phase during the recrystallization process at 700–1000

$^\circ\text{C}$ . Thus, it can be concluded that  $\text{SrCu}_2\text{SnS}_4$  exhibits the two polymorphs with phase-transformation temperature from  $\alpha$ - to  $\beta$ -phase of 672  $^\circ\text{C}$ . As for one IR NLO material, important physicochemical properties including band gap, SHG response, laser damage threshold (LDT), and birefringence should be systematically studied. In this work, based on the polycrystalline samples, their UV–visible diffuse reflectance spectra were recorded and the result shows that the band gaps of  $\alpha$ - and  $\beta$ -phases are 2.01 and 2.06 eV (Figure 2c), respectively, which are similar to that of  $\text{BaCu}_2\text{SnS}_4$  (1.96 eV) and still larger than that of commercialized  $\text{ZnGeP}_2$  or  $\text{AgGaSe}_2$  crystals.<sup>59,60</sup> Powder laser damage thresholds (LDTs) were also measured under 1.06  $\mu\text{m}$  laser, and title crystals exhibit about 2.3 times that of  $\text{AgGaSe}_2$  (as the reference), which shows that they may sustain the high-power laser radiation and have the potential to be applied in the laser frequency downconversion system under around 1  $\mu\text{m}$  common Nd- or Yb-doped YAG laser irradiation (Table S4).<sup>34</sup> We measured the infrared (IR) spectra for title crystals (Figure S3); it is clear that there were no obvious absorption peaks in the range from 4000 to 500  $\text{cm}^{-1}$ , indicating that they exhibit a wide IR transmission region up to 20  $\mu\text{m}$  (500  $\text{cm}^{-1}$ ). To further analyze the intrinsic effect on material band gaps, we have also calculated their band structures and partial density of states (PDOS) based on the first-principles calculation. Their theoretical band gaps are 1.08 ( $\alpha$ : direct band gap) and 1.14 eV ( $\beta$ : indirect band gap), respectively, which are smaller than the experimental values owing to the discontinuity of the exchange-correlation energy in GGA calculation<sup>61</sup> (Figure S4). Besides, both of them also possess similar PDOS diagram (Figure 3a,b). As for  $\beta$ -phase, the region from  $-15$  to  $-10$  eV is mainly occupied by the S 2s and Sn 5s,5p orbitals, with a minor contribution from Cu 4p orbitals. Besides, the range from  $-7.5$  eV to the Fermi level in the valence bands could be considered as the main contribution of S 3p with Cu 4s and Sn 5p orbitals. Also, S 3p and Sn 5s orbitals are the main contributors to the bottom of conduction bands. Therefore, the optical absorption for title crystals originates from the combined action of two anionic groups ( $\text{CuS}_4$  and  $\text{SnS}_4$ ). In



comparison with those of the previously reported  $\text{SrA}_2\text{SnS}_4$  ( $A = \text{Li}, \text{Na}$ ) well-known analogues,<sup>62</sup> the experimental and theoretical band gaps of title crystals are smaller, which also verifies that the effect of alkali metal atoms on band gap can be negligible and their optical absorptions are only determined by the  $\text{SnS}_4$  ligand. To verify the application potential in the IR region, the SHG responses at 2.09  $\mu\text{m}$  fundamental light irradiation for title crystals have been also investigated (Figure 2e,f). With the increase of particle sizes of microcrystalline samples, their SHG intensities show the same increase, indicating that they satisfy the essential phase-matching (PM) condition. Generally, birefringence as a critical parameter can be used to estimate the phase-matching capability and the optional magnitude ( $\Delta n$ ) should satisfy the suggested range from 0.03 to 0.10. Herein, we have also calculated their refractive index variation with wavelengths and their birefringences ( $\Delta n$ ) were calculated to be 0.053 ( $\alpha$ ) and 0.065 ( $\beta$ ) at 1  $\mu\text{m}$  or 0.035 ( $\alpha$ ) and 0.047 ( $\beta$ ) at 2  $\mu\text{m}$ , respectively, which are well situated within the above limited range and consistent with the experimental PM results (Figure 2d). Besides, in comparison with benchmark  $\text{AgGaS}_2$ , the maximum SHG intensities at 200–250  $\mu\text{m}$  particle sizes are about  $0.7 \times \text{AgGaS}_2$  for  $\alpha$ -phase and  $1.0 \times \text{AgGaS}_2$  for  $\beta$ -phase, which are comparable to the SHG values of other famous IR NLO crystals, such as  $\text{LiInS}_2$  ( $0.56 \times \text{AgGaS}_2$ ),<sup>63,64</sup>  $\text{LiGaSe}_2$  ( $0.76 \times \text{AgGaS}_2$ ),<sup>63,65</sup>  $\text{LiInSe}_2$  ( $0.9 \times \text{AgGaS}_2$ ),<sup>66</sup> and  $\text{BaGa}_4\text{S}_7$  ( $1.0 \times \text{AgGaS}_2$ ).<sup>67</sup> We have also calculated the theoretical NLO coefficients for title crystals, and their calculated maximum values are  $-9.0$  pm/V for  $\alpha$ -phase and  $9.4$  pm/V for  $\beta$ -phase, which also match well with the experimental values.

As for the origin of the NLO effect in title crystals, we also used the SHG density calculation to analyze the contribution of anionic ligands. According to the result of SHG density, it can be concluded that their SHG effects originate from the cooperative influence of  $\text{CuS}_4$  and  $\text{SnS}_4$  tetrahedral groups and the introduction of Cu (or other  $d^{10}$ -elements) into crystal structures generates much improvement in NLO performances of IR materials (Figure 3c–f). In view of the polar space group ( $Ama2$ ) for  $\beta$ -phase, dipole moment calculations were also chosen to study the origin of the SHG effect (Table S6). The result shows that the whole dipole moment is 24.81 D for  $\beta$ -phase, and the direction of polarization for all anionic groups in  $\beta$ -phase is along the  $z$ -axis, with the other two directions ( $x$  and  $y$ ) canceling out to zero. The dipole moment of each anionic group is about 11.98 D for  $\text{CuS}_4$  and 27.6 D for  $\text{SnS}_4$ , which produce the main role in the SHG effect. Thus, the coupling effect of two anionic groups ( $\text{CuS}_4$  and  $\text{SnS}_4$ ) offers the main contribution to the SHG origin of title crystals. Compared with the physicochemical properties of other polymorphisms in the related  $\text{I}_2$ –II–IV–VI<sub>4</sub> DLSs system, such as  $\text{Cu}_2\text{ZnSiS}_4$ <sup>42</sup> and  $\text{Li}_2\text{MnSnS}_4$ ,<sup>43</sup> both the phases exhibit similar band gaps and SHG responses, indicating that structural transitions produce no obvious effect on the NLO performances of polymorphisms (Table S5). Based on the above research, title crystals exhibit strong SHG responses ( $\sim 0.7$  and  $1.0 \times \text{AgGaS}_2$ ) with essential PM behavior and large LDTs ( $2.3 \times \text{AgGaS}_2$ ), indicating them as promising IR NLO crystals (Table 1). We have summarized the optical performances (band gap and SHG effect) of the  $\text{I}_2$ –Ba/Sr/Pb/Eu–IV–Q<sub>4</sub> system (Table S7).

In summary, new polymorphs,  $\alpha$ - and  $\beta$ - $\text{SrCu}_2\text{SnS}_4$  ( $\alpha$ :  $P3_21$  vs  $\beta$ :  $Ama2$ ), were successfully synthesized. Structural

**Table 1. Performance Comparison between Title Crystals and  $\text{AgGaS}_2$  (as the Reference, AGS) Including,  $d_{ij}$  as the Calculated NLO Coefficients**

compounds	$\alpha$ -phase	$\beta$ -phase	$\text{AgGaS}_2$ <sup>63,68</sup>
space group	$P3_21$	$Ama2$	$I42d$
band gap (eV)	2.01	2.06	2.64
SHG response ( $\times$ AGS)	$\sim 0.7$	$\sim 1.0$	1.0
maximum $d_{ij}$ (pm/V)	$-9.0$	9.4	13.0
LDT ( $\times$ AGS)	$\sim 2.3$	$\sim 2.3$	1.0
birefringence ( $\Delta n@1 \mu\text{m}$ )	0.053	0.065	0.039

differences between title crystals were compared, and this structural transition can be considered as the variable arrangement directions of  $\text{CuS}_4$  units, which also produce a good inspiration in designing new polymorphisms. An investigation of the physicochemical properties shows that title crystals exhibit excellent performances including reliable chemical stability, strong SHG responses ( $\sim 0.7$  and  $1.0 \times \text{AgGaS}_2$ ), high LDTs, required PM behavior, and suitable  $\Delta n$  as promising IR NLO materials in comparison with commercial  $\text{AgGaS}_2$ . An analysis of the origin of SHG effects based on two calculation methods (dipole moment and SHG density) shows that the above two calculated results agree well and the SHG effects of both of them are derived from the synergetic contribution of  $\text{CuS}_4$  and  $\text{SnS}_4$  anionic groups.

## EXPERIMENTAL SECTION

Spontaneous crystallization processes of title compounds were completed in the vacuum-sealed silica tubes under different sintering temperatures. Selected high-quality crystals were used for data collection on a Bruker SMART APEX II 4K CCD diffractometer using Mo  $K\alpha$  radiation ( $\lambda = 0.71073 \text{ \AA}$ ) at 296 K. Powder X-ray diffraction (XRD) patterns of title compounds were collected on a Bruker D2 X-ray diffractometer with Cu  $K\alpha$  radiation ( $\lambda = 1.5418 \text{ \AA}$ ) at room temperature. Diffuse-reflectance spectra were measured by a Shimadzu SolidSpec-3700DUV spectrophotometer in the wavelength range of 200–2600 nm at room temperature. IR spectra of title polymorphs were investigated within the range from 4000 to 400  $\text{cm}^{-1}$ . A HCT-2 (HENVEN) thermal analyzer was used to investigate their differential scanning calorimetric (DSC) curves. Powder SHG responses were investigated by a Q-switch laser (2.09  $\mu\text{m}$ , 3 Hz, 50 ns) under six different particle sizes with  $\text{AgGaS}_2$  as the reference. LDTs of title compounds were evaluated on powder samples (150–200  $\mu\text{m}$ ) with a pulsed YAG laser. Electronic structures and theoretical performances were studied by density functional theory (DFT) based on ab initio calculations (details in the Supporting Information).

## ASSOCIATED CONTENT

### Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acs.chemmater.9b04842>.

Synthesis, measurements, crystal data, structural comparison, bond valence and GII, LDT, and performance comparisons, DSC curves, PXRD at different temperatures, IR spectra, and band structures of title crystals (PDF)

Datablock 1, ellipsoid plot (ZIP)

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## Author Contributions

The manuscript was written through contributions of all the authors.

## Notes

The authors declare no competing financial interest.

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